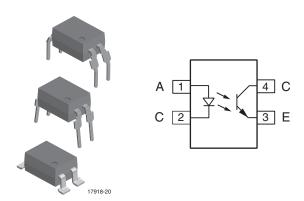


# Optocoupler, Phototransistor Output, High Reliability, 5300 V<sub>RMS</sub>



### **DESCRIPTION**

The SFH615A feature a variety of transfer ratios, low coupling capacitance and high isolation voltage. These couplers have a GaAs infrared diode emitter, which is optically coupled to a silicon planar phototransistor detector, and is incorporated in a plastic DIP-4 package.

The coupling devices are designed for signal transmission between two electrically separated circuits.

The couplers are end-stackable with 2.54 mm lead spacing. Creepage and clearance distances of > 8 mm are achieved with option 6. This version complies with IEC 60950 (DIN VDE 0805) for reinforced insulation up to an operation voltage of 400  $V_{RMS}$  or DC. Specifications subject to change.

#### **FEATURES**

 Excellent CTR linearity depending on forward current



- Isolation test voltage, 5300 V<sub>RMS</sub>
- Fast switching times
- Low CTR degradation
- · Low coupling capacitance
- Material categorization: for definitions of compliance please see www.vishav.com/doc?99912



FREE GREEN (5-2008)

#### **APPLICATIONS**

- Switchmode power supply
- Telecom
- · Battery powered equipment

#### **AGENCY APPROVALS**

- UL file no. E52744
- cUL tested to CSA 22.2 bulletin 5A
- DIN EN 60747-5-5 (VDE 0884-5) available with option 1
- BSI EN 60950; EN 60065
- FIMKO
- CQC

ORDERING INFORMATION						
S F H 6 1 5 A - # X 0 # # T  PART NUMBER  CTR PACKAGE OPTION TAPE AND REEL  Option 7  Option 9						
AGENCY CERTIFIED/PACKAGE	PACKAGE CTR (%)					
UL, cUL, BSI, FIMKO	40 to 80	63 to 125	100 to 200	160 to 320		
DIP-4	SFH615A-1	SFH615A-2	SFH615A-3	SFH615A-4		
DIP-4, 400 mil, option 6	SFH615A-1X006	SFH615A-2X006	SFH615A-3X006	-		
SMD-4, option 7	-	-	SFH615A-3X007T <sup>(1)</sup> -			
SMD-4, option 9	=	SFH615A-2X009T	SFH615A-3X009T (1)	SFH615A-4X009		
UL, cUL, VDE, BSI, FIMKO	40 to 80	63 to 125	100 to 200	160 to 320		
DIP-4	SFH615A-1X001	SFH615A-2X001	SFH615A-3X001	SFH615A-4X001		
DIP-4, 400 mil, option 6	SFH615A-1X016	SFH615A-2X016	SFH615A-3X016	SFH615A-4X016		
SMD-4, option 7	SFH615A-1X017T (1)	SFH615A-2X017T (1)	SFH615A-3X017	SFH615A-4X017T (1)		
SMD 4 option 0		SFH615A-2X019T				
SMD-4, option 9	-	SFH615A-2X019T3 (2)	-	-		

#### Notes

- Additional options may be possible, please contact sales office.
- (1) Also available in tubes; do not add T to end.
- (2) T3 rotation in tape and reel packaging.



ABSOLUTE MAXIMUM RATINGS (T <sub>amb</sub> = 25 °C, unless otherwise specified)							
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT			
INPUT							
Reverse voltage		V <sub>R</sub>	6	V			
DC forward current		I <sub>F</sub>	60	mA			
Forward surge current	t <sub>p</sub> ≤ 10 μs	I <sub>FSM</sub>	2.5	Α			
LED power dissipation	at 25 °C	P <sub>diss</sub>	70	mW			
OUTPUT							
Collector emitter voltage		V <sub>CEO</sub>	70	V			
Emitter collector voltage		V <sub>ECO</sub>	7	V			
Collector current		I <sub>C</sub>	50	mA			
Collector peak current	$t_p/T = 0.5, t_p \le 10 \text{ ms}$	Ісм	100	mA			
Ouput power dissipation	at 25 °C	P <sub>diss</sub>	150	mW			
COUPLER							
Operation temperature		T <sub>amb</sub>	-55 to +100	°C			
Storage temperature range		T <sub>stg</sub>	-55 to +150	°C			
Soldering temperature (1)	2 mm from case, ≤ 10 s	T <sub>sld</sub>	260	°C			

#### **Notes**

- Stresses in excess of the absolute maximum ratings can cause permanent damage to the device. Functional operation of the device is not
  implied at these or any other conditions in excess of those given in the operational sections of this document. Exposure to absolute
  maximum ratings for extended periods of the time can adversely affect reliability.
- (1) Refer to reflow profile for soldering conditions for surface mounted devices (SMD). Refer to wave profile for soldering conditions for through hole devices (DIP).

<b>ELECTRICAL CHARACTERISTICS</b> (T <sub>amb</sub> = 25 °C, unless otherwise specified)							
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT
INPUT							
Forward voltage	$I_F = 60 \text{ mA}$		$V_{F}$		1.35	1.65	٧
Reverse current	V <sub>R</sub> = 6 V		I <sub>R</sub>		0.01	10	μΑ
Capacitance	$V_R = 0 V, f = 1 MHz$		Co		13		pF
OUTPUT							
Collector emitter capacitance	$V_{CE} = 5 \text{ V}, f = 1 \text{ MHz}$		C <sub>CE</sub>		5.2		pF
		SFH615A-1	I <sub>CEO</sub>		2	50	nA
Collector emitter leakage current	V <sub>CF</sub> = 10 V	SFH615A-2	I <sub>CEO</sub>		2	50	nA
Collector entitter leakage current	ACE = 10 A	SFH615A-3	I <sub>CEO</sub>		5	100	nA
		SFH615A-4	I <sub>CEO</sub>		5	100	nA
COUPLER							
Collector emitter saturation voltage	I <sub>F</sub> = 10 mA, f = 1 MHz		V <sub>CEsat</sub>		0.25	0.4	V
Coupling capacitance			C <sub>C</sub>		0.4		pF

#### Note

Minimum and maximum values are testing requirements. Typical values are characteristics of the device and are the result of engineering
evaluation. Typical values are for information only and are not part of the testing requirements.



CURRENT TRANSFER RATIO (T <sub>amb</sub> = 25 °C, unless otherwise specified)								
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT	
		SFH615A-1	CTR	40 80	%			
	$I_{E} = 10 \text{ mA}, V_{CE} = 5 \text{ V}$	SFH615A-2	CTR	63		125	%	
	$I_F = 10 \text{ H/A}, V_{CE} = 5 \text{ V}$	SFH615A-3	CTR	100		200	%	
I <sub>C</sub> /I <sub>E</sub>		SFH615A-4	CTR	160		320	%	
IC/1F		SFH615A-1	CTR	13	30		%	
	1 1 0 1/ 5 1/	SFH615A-2	CTR	22	45		%	
	$I_F = 1 \text{ mA}, V_{CE} = 5 \text{ V}$	SFH615A-3	CTR	34	70		%	
		SFH615A-4	CTR	56	90		%	

PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT
NON-SATURATED							
Turn-on time	$I_F = 10 \text{ mA}, V_{CC} = 5 \text{ V}, R_L = 75 \Omega$		t <sub>on</sub>		3		μs
Rise time	$I_F = 10 \text{ mA}, V_{CC} = 5 \text{ V}, R_L = 75 \Omega$		t <sub>r</sub>		2		μs
Turn-off time	$I_F = 10 \text{ mA}, V_{CC} = 5 \text{ V}, R_L = 75 \Omega$		t <sub>off</sub>		2.3		μs
Fall time	$I_F = 10 \text{ mA}, V_{CC} = 5 \text{ V}, R_L = 75 \Omega$		t <sub>f</sub>		2		μs
Cut-off frequency	$I_F = 10 \text{ mA}, V_{CC} = 5 \text{ V}, R_L = 75 \Omega$		f <sub>CO</sub>		208		kHz
SATURATED							
	I <sub>F</sub> = 20 mA	SFH615A-1	t <sub>on</sub>		3		μs
T !!	1 40 1	SFH615A-2	t <sub>on</sub>		4.2		μs
Turn-on time	I <sub>F</sub> = 10 mA	mA SFH615A-1 t <sub>on</sub> mA SFH615A-2 t <sub>on</sub> SFH615A-3 t <sub>on</sub> mA SFH615A-4 t <sub>on</sub> mA SFH615A-1 t <sub>r</sub> mA SFH615A-2 t <sub>r</sub> SFH615A-2 t <sub>r</sub> SFH615A-3 t <sub>r</sub>		4.2		μs	
	I <sub>F</sub> = 5 mA	SFH615A-4	t <sub>on</sub>		6		μs
	I <sub>F</sub> = 20 mA	SFH615A-1	t <sub>r</sub>		2		μs
Rise time		SFH615A-2	t <sub>r</sub>		3		μs
Rise time	I <sub>F</sub> = 10 mA	SFH615A-3	t <sub>r</sub>		3		μs
	I <sub>F</sub> = 5 mA	SFH615A-4	t <sub>r</sub>		4		μs
	I <sub>F</sub> = 20 mA	SFH615A-1	t <sub>off</sub>		18		μs
Turn-off time	1 10	SFH615A-2	t <sub>off</sub>		23		μs
rum-on ume	I <sub>F</sub> = 10 mA	SFH615A-3	t <sub>off</sub>		23		μs
	I <sub>F</sub> = 5 mA	SFH615A-4	t <sub>off</sub>		25		μs
	I <sub>F</sub> = 20 mA	SFH615A-1	t <sub>f</sub>		11		μs
Fall times	1 10 mA	SFH615A-2	t <sub>f</sub>		14		μs
Fall time	I <sub>F</sub> = 10 mA	SFH615A-3	t <sub>f</sub>		14		μs
	I <sub>F</sub> = 5 mA	SFH615A-4	t <sub>f</sub>		15		μs



### www.vishay.com

## Vishay Semiconductors

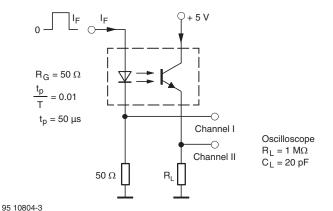


Fig. 1 - Test Circuit, Non-Saturated Operation

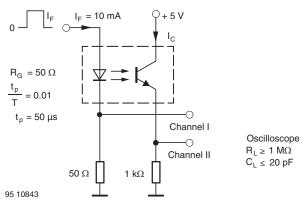


Fig. 2 - Test Circuit, Saturated Operation

I <sub>F</sub>			
o <del>-</del>	<b>▼</b> t <sub>p</sub> −	<b>→</b>	t
100 %			
90 %			
10 %	$\cup$	$\rightarrow$	
0 —	t <sub>d</sub> t <sub>r</sub>	t <sub>s</sub> t <sub>off</sub>	t
t <sub>p</sub> t <sub>d</sub> t <sub>r</sub>	Pulse duration Delay time Rise time	$t_s$ $t_f$ $t_{off}$ (= $t_s + t_f$ )	Storage time Fall time Turn-off time
$t_{on} (= t_d + t_r)$	Turn-on time		96 11698

Fig. 3 - Switching Times

PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT
Climatic classification	According to IEC 68 part 1		55/115/21	
Pollution degree	According to DIN VDE 0109		2	
Comparative tracking index	Insulation group IIIa	CTI	175	
Maximum rated withstanding isolation voltage	According to UL1577, t = 1 min	V <sub>ISO</sub>	4470	V <sub>RMS</sub>
Tested withstanding isolation voltage	According to UL1577, t = 1 s	V <sub>ISO</sub>	5300	V <sub>RMS</sub>
Maximum transient isolation voltage	According to DIN EN 60747-5-5	V <sub>IOTM</sub>	8000	V <sub>peak</sub>
Maximum repetitive peak isolation voltage	According to DIN EN 60747-5-5	V <sub>IORM</sub>	890	V <sub>peak</sub>
Isolation resistance	T <sub>amb</sub> = 25 °C, V <sub>IO</sub> = 500 V	R <sub>IO</sub>	≥ 10 <sup>12</sup>	Ω
Isolation resistance	$T_{amb} = 100  ^{\circ}\text{C},  V_{IO} = 500  \text{V}$	R <sub>IO</sub>	≥ 10 <sup>11</sup>	Ω
Output safety power		P <sub>SO</sub>	700	mW
Input safety current		I <sub>SI</sub>	400	mA
Input safety temperature		T <sub>S</sub>	175	°C
Creepage distance	DIP-4		≥ 7	mm
Clearance distance	DIP-4		≥ 7	mm
Creepage distance	DIP-4, 400 mil, option 6		≥ 8	mm
Clearance distance	DIP-4, 400 mil, option 6		≥ 8	mm
Creepage distance	SMD-4, option 7 and option 9		≥ 7	mm
Clearance distance	SMD-4, option 7 and option 9		≥ 7	mm
Insulation thickness		DTI	≥ 0.4	mm

#### Note

• As per DIN EN 60747-5-5, § 7.4.3.8.2, this optocoupler is suitable for "safe electrical insulation" only within the safety ratings. Compliance with the safety ratings shall be ensured by means of protective circuits.



### TYPICAL CHARACTERISTICS (T<sub>amb</sub> = 25 °C, unless otherwise specified)

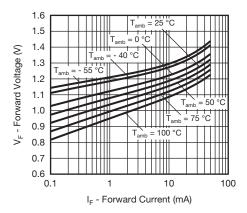


Fig. 4 - Forward Voltage vs. Forward Current

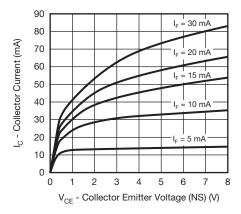


Fig. 5 - Collector Current vs. Collector Emitter Voltage (non-saturated)

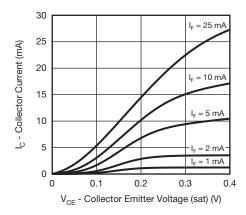


Fig. 6 - Collector Current vs. Collector Emitter Voltage (saturated)

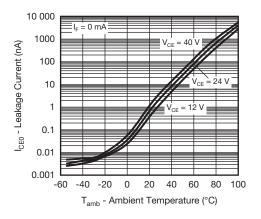


Fig. 7 - Leakage Current vs. Ambient Temperature

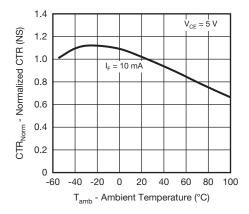


Fig. 8 - Normalized CTR (non-saturated) vs. Ambient Temperature

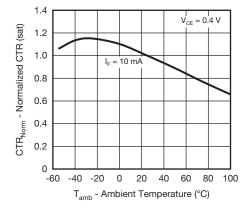


Fig. 9 - Normalized CTR (saturated) vs. Ambient Temperature





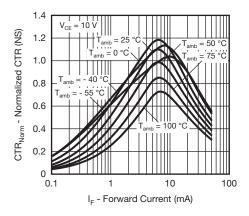


Fig. 10 - Normalized CTR (non-saturated) vs. Forward Current

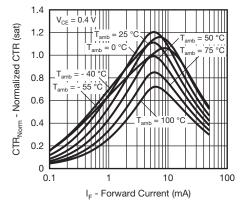


Fig. 11 - Normalized CTR (saturated) vs. Forward Current

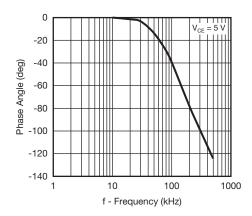


Fig. 12 - Phase Angle vs. Frequency

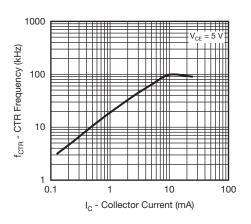


Fig. 13 - Cut-Off Frequency vs. Collector Current

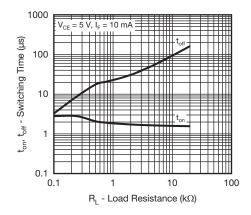


Fig. 14 - Switching Time vs. Load Resistance

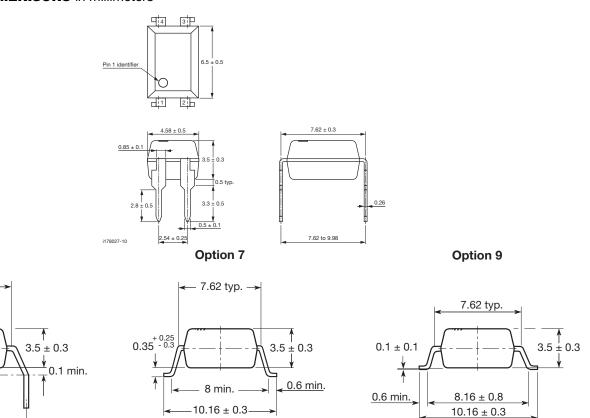


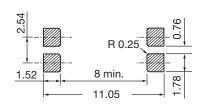
Option 6

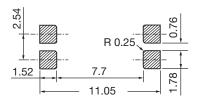
7.62 typ.-

## Vishay Semiconductors

### **PACKAGE DIMENISONS** in millimeters







20802-28

2.7 min.

- 10.16 typ.

### **PACKAGE MARKING (Example)**



#### **Notes**

- VDE logo is only marked on option 1 parts. Option information is not marked on the part.
- Tape and reel suffix (T) is not part of the package marking.

### **PACKING INFORMATION**

DEVICE PER TUBE						
TYPE	UNITS/TUBE	TUBES/BOX	UNITS/BOX			
DIP-4	100	40	4000			

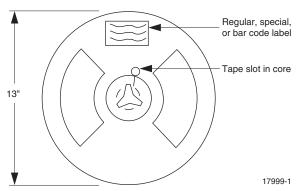


Fig. 15 - Tape and Reel Shipping Medium

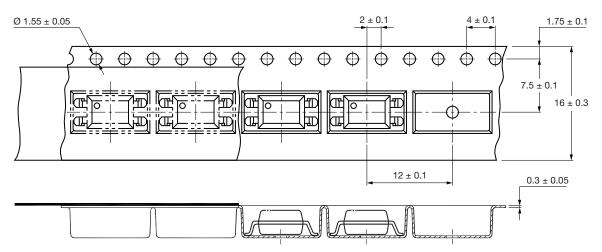


Fig. 16 - Tape and Packing for Option 7 and Option 9

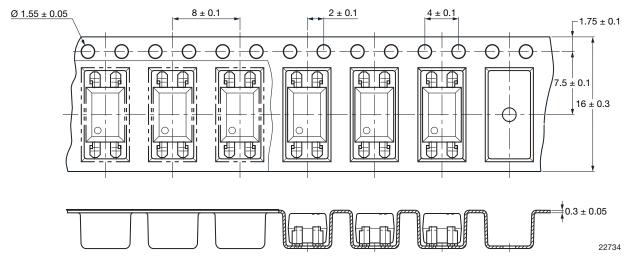


Fig. 17 - Tape Packing for Option 7 and Option 9, T3 Rotation (2000 units per reel)



### **SOLDER PROFILES**

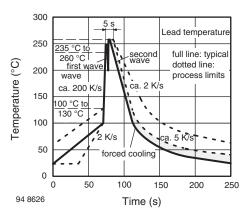


Fig. 18 - Wave Soldering Double Wave Profile According to J-STD-020 for DIP-8 Devices

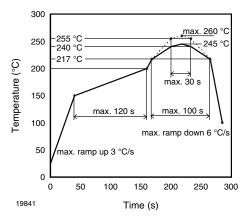


Fig. 19 - Lead (Pb)-free Reflow Solder Profile According to J-STD-020 for SMD-8 Devices

### HANDLING AND STORAGE CONDITIONS

ESD level: HBM class 2 Floor life: unlimited

Conditions:  $T_{amb}$  < 30 °C, RH < 85 %

Moisture sensitivity level 1, according to J-STD-020



## **Legal Disclaimer Notice**

Vishay

### **Disclaimer**

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Vishay Intertechnology, Inc. hereby certifies that all its products that are identified as RoHS-Compliant fulfill the definitions and restrictions defined under Directive 2011/65/EU of The European Parliament and of the Council of June 8, 2011 on the restriction of the use of certain hazardous substances in electrical and electronic equipment (EEE) - recast, unless otherwise specified as non-compliant.

Please note that some Vishay documentation may still make reference to RoHS Directive 2002/95/EC. We confirm that all the products identified as being compliant to Directive 2002/95/EC conform to Directive 2011/65/EU.

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Revision: 02-Oct-12 Document Number: 91000